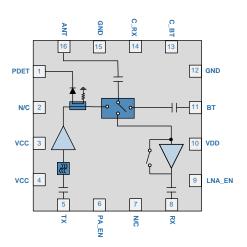


# **RFFM4203**

3.0V to 5.0V, 2.4GHz to 2.5GHz 802.11b/g/n/ac WiFi Front End Module

The RFFM4203 provides a complete integrated solution in a single front end module (FEM) for WiFi 802.11b/g/n/ac and Bluetooth® systems. The ultra-small form factor and integrated matching greatly reduces the number of external components and layout area in the customer application. This simplifies the total front end solution by reducing the bill of materials, system footprint, and manufacturability cost. The RFFM4203 integrates a 2.4GHz to 2.5GHz power amplifier (PA), low noise amplifier (LNA) with bypass mode, power detector coupler for improved accuracy, and some filtering for harmonic rejection. The device is provided in a 3mm x 3mm x 1.05mm, 16-pin package. This module meets or exceeds the RF front end needs of IEEE 802.11b/g/n/ac WiFi RF systems.



Functional Block Diagram

## **Ordering Information**

RFFM4203SB	Standard 5 piece bag
RFFM4203SQ	Standard 25 piece bag
RFFM4203SR	Standard 100 piece reel
RFFM4203TR7	Standard 2500 piece reel
RFFM4203PCK-410	Fully assembled evaluation board w/ 5 piece bag



Package: Laminate, 16-pin, 3.0mm x 3.0mm x 1.05mm

#### **Features**

- Integrated 2.4GHz to 2.5GHz b/g/n/ac Amplifier, LNA with Bypass Mode, SP3T Switch, and Power Detector Coupler
- Single Supply Voltage 3.0V to 5V
- P<sub>OUT</sub> = 21.5dBm, 5V <3% Dynamic EVM
- P<sub>OUT</sub> = 19dBm, 3.3V <3% Dynamic EVM

## **Applications**

- IEEE802.11b/g/n/ac WiFi Applications
- 2.4GHz to 2.5GHz ISM Band Solutions
- Portable Battery-Powered Equipment
- WiFi Access Points, Gateways, and Set Top Boxes



### **Absolute Maximum Ratings**

Parameter	Rating	Unit
DC Supply Voltage (Continuous with No Damage)	5.4	V
DC Supply Current	500	mA
Operating Temperature Range	-40 to +85	°C
Storage Temperature	-40 to +150	°C
Maximum Tx Input Power into 50W Load	+10	dBm
Maximum Rx Input Power for both High Gain and Bypass Modes (No Damage)	+10	dBm
Moisture Sensitivity	MSL3	



Caution! ESD sensitive device.



RFMD Green: RoHS status based on EU Directive 2011/65/EU (at time of this document revision), halogen free per IEC 61249-2-21, < 1000ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

### **Nominal Operating Parameters**

Barrantan	Specification			11-2	0.000	
Parameter	Min	Тур	Max	Unit	Condition	
Typical Condition 3.3V					Temperature = -10°C to +70°C, V <sub>CC</sub> = 3.3V, PA_EN = High, P <sub>OUT</sub> = 19dBm using an IEEE802.11n MCS7 waveform unless otherwise noted.	
Tx Performance - 11g/n/ac					Compliance with standard 802.11g/n/ac	
Frequency	2412		2484	MHz		
802.11n Output Power	18.5	19		dBm	802.11n HT20 and HT40 MCS7 at 25°C	
11n Dynamic EVM		2.5	3	%		
		-32	-30.5	dB		
802.11ac Output Power	16.5	17		dBm	802.11ac HT40 MCS9 at 25°C	
11ac Dynamic EVM		1.5	1.8	%		
			-35	dB		
Tx Performance - Spectral Mask						
802.11n Output Power		21		dBm	802.11n HT20 and HT40 MCS7 at 25°C	
802.11b Output Power		24		dBm	Meet 802.11b DSSS 1Mbps Spectral Mask	
General Tx Performance						
Second Harmonic		-24	-20	dBm/MHz	At P <sub>OUT</sub> = 19dBm	
Third Harmonic		-50	-42	dBm/MHz		
Gain	25	27	29	dB		
Gain Variation Over Temp	-2		+2	dB		
Power Detect Voltage	0.11	0.125	.014	V	RF = off	
	0.7	0.8	0.9	V	At rated P <sub>OUT</sub>	
Power Detect Accuracy	-2.0		+2.0	dB	Into 3:1 VSWR load at 25°C	
Input Return Loss - Tx_in pin		-13	-10	dB	In specified frequency band	
Output Return Loss at ANT pin		-15	-10	dB		
Operating Current		210	230	mA	At rated P <sub>OUT</sub> 19dBm	
		195	215	mA	At rated P <sub>OUT</sub> 17dBm	
Quiescent Current		170		mA	Nominal conditions; no RF applied	
Leakage Current		2	10	μA	V <sub>CC</sub> = 3.3V, PA_EN = Low, C_RX = Low, LNA_EN = Low	
Power Added Efficiency		10.5		%	Nominal conditions	
Power Supply - V <sub>CC</sub>	3.0	3.3	3.6	V		



Parameter	Specification				1	
Parameter	Min	Тур	Max	Unit	Condition	
Typical Condition 3.3V (continued)					Temperature = -10°C to +70°C, V <sub>CC</sub> = 3.3V, PA_EN = High, P <sub>OUT</sub> = 19dBm using an IEEE802.11n MCS7 waveform unless otherwise noted.	
VCONTROL High (PA_EN, C_RX, C_BT, LNA_EN)	2.8	3	V <sub>cc</sub>	V		
VCONTROL Low (PA_EN, C_RX, C_BT, LNA_EN)	0		0.2	V		
Turn-on time from PA_EN edge			500	ns	Output stable to within 90% of final gain	
Turn-off time from PA_EN edge			500	ns		
Stability	-25		24	dBm	No spurs above -47dBm into 4:1 VSWR	
CW P1dB	26	27		dBm	Tx mode in 50% Duty Cycle	
Rx Performance					Temperature = -10°C to +70°C, V <sub>DD</sub> = 3.3V,	
TX Ferrormance					C_RX = High, LNA_EN = High	
Gain	11	13	15	dB		
NF		2.3	3	dB	In specified frequency band	
RX Port Return Loss			-9.6	dB		
ANT Port Return Loss			-4	dB		
Input IP3	4	8		dBm		
Input P1dB	-6	-2		dBm		
I <sub>DD</sub>		10	15	mA		
LNA_EN Control Current		30	75	μA		
Rx Bypass Mode					Temperature = -10°C to +70°C, V <sub>DD</sub> = 3.3V, C_RX = Low, LNA_EN = Low	
Insertion Loss	-8.5	-7.5	-6.5	dB		
RX Port Return Loss			-9.6	dB		
ANT Port Return Loss			-4	dB		
Input IP3	4	8		dB		
Input P1dB	-6	-2		dBm		
Typical Condition 5.0V					Temperature = -10°C to +70°C, V <sub>CC</sub> = 5.0V, PA_EN = High, P <sub>OUT</sub> = 21.5dBm using a IEEE802.11n MCS7 waveform unless otherwise noted.	
Tx Performance - 11g/n/ac					Compliance with standard 802.11g/n/ac	
Frequency	2412		2484	MHz		
802.11n Output Power	21	21.5		dBm	802.11n HT20 and HT40 MCS7 at 25°C	
11n Dynamic EVM		2.5	3	%		
•		-32	-30.5	dB		
802.11ac Output Power	17	18		dBm	802.11ac HT40 MCS9 at 25°C	
11ac Dynamic EVM		1.5	1.8	%		
<b>,</b>			-35	dB		
Tx Performance - Spectral Mask						
802.11n output power		22		dBm	802.11n HT20 and HT40 MCS7 at 25°C	
802.11b output power		26		dBm	Meet 802.11b DSSS 1Mbps spectral mask	



Parameter	Specification			11-26	0. 191	
rarameter	Min	Тур	Max	Unit	Condition	
Typical Condition 5.0V (continued)					Temperature = -10°C to +70°C, V <sub>CC</sub> = 5.0V, PA_EN = High, P <sub>OUT</sub> = 21.5dBm using a IEEE802.11n MCS7 waveform unless otherwise noted.	
General Tx Performance						
Second Harmonic		-20	-18	dBm/MHz	P <sub>OUT</sub> = 21.5dBm	
Third Harmonic		-43	-38	dBm/MHz		
Gain	25	27	29	dB		
Gain variation over Temp	-2		+2	dB		
Power Detect Voltage	0.14	0.16	0.18	V	P <sub>OUT</sub> = 0dBm and also when RF = off	
Power Detect Accuracy	-2		+2	dB	Into 3:1 VSWR load at 25°C	
Power Detect Voltage	0.95	1.05	1.20	V	P <sub>OUT</sub> = 21.5dBm	
Input Return Loss - Tx_in pin		-13	-10	dB	In specified frequency band	
Output Return Loss at ANT pin		-15	-10	dB		
Operating Current		260	290	mA	At rated 11n P <sub>OUT</sub>	
		230	260	mA	At rated P <sub>OUT</sub> 19dBm	
Quiescent Current		190		mA	Nominal conditions; no RF applied	
Leakage Current		2	10	μΑ	V <sub>CC</sub> = 5V, PA_EN = low, C_RX = low, LNA_EN = low at 25°C	
VCONTROL High (PA_EN, C_BT, C_RX, LNA_EN)	2.8	2.9	5.0	V		
VCONTROL Low (PA_EN, C_BT, C_RX, LNA_EN)	0		0.2	V		
Turn-on time from PA_EN edge			500	ns	Output stable to within 90% of final gain	
Turn-off time from PA_EN edge			500	ns		
Stability	-25		24	dBm	No spurs above -47dBm into 4:1 VSWR	
CW P1dB	28.5	29.5		dBm	Tx mode in 50% duty cycle	
Rx Performance					Temperature = -10°C to +70°C, V <sub>DD</sub> = 5.0V, C_RX = High, LNA_EN = High	
Gain	11.5	14	16	dB		
NF		2.3	3.0	dB	In specified frequency band	
RX Port Return Loss			-9.6	dB		
ANT Port Return Loss			-4	dB		
Input IP3	4	8		dBm		
Input P1dB	-6	-2		dBm		
IDD		10	20	mA		
LNA_EN Control Current		30	50	μΑ		
Rx Bypass Mode					Temperature = -10°C to +70°C, V <sub>DD</sub> = 5.0V, C_RX = High, LNA_EN = Low	
Insertion Loss	-8.5	-7.5	-6.5	dB		
RX Port Return Loss	5.5	7.5	-9.6	dB		
ANT Port Return Loss			-9.0 -4	dB		
Input IP3	4	8	-7	dB		
Input P1dB	-6	-2		dBm		

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Parameter	Specification			11-26		
Parameter	Min	Тур	Max	Unit	Condition	
General Performance 3.3V and 5.0V						
Control Current						
C_RX and C_BT Current		0.5	1	μA		
PA_EN Current		30	50	μA		
Switch Control Speed			200	ns		
PA_EN Control Impedance		5.2		МΩ		
LNA_EN Control Impedance		7.4		МΩ		
C_RX Control Impedance		27		МΩ		
C_BT Control Impedance		27		МΩ		
ESD						
Human Body Model	500			V	EIA/JESD22-114A RF pins	
	1000			V	EIA/JESD22-114A DC pins	
Charge Device Model	250			V	JESD22-C101C all pins	
Thermal Resistance (Th-j)		46		°C/W	Vcc=3.3V; Pout=20dBm; 100% duty cycle	
		56		°C/W	Vcc=5V; Pout=22dBm; 100% duty cycle	
Junction Temperature (TJ)		118		°C	Vcc=3.3V; Pout=20dBm; 100% duty cycle	
. , ,		59		°C	Vcc=5V; Pout=22dBm; 100% duty cycle	
Maximum Input Power			12	dBm	Into $50\Omega$ , $V_{CC} = 3.3V$ , $25^{\circ}C$	
Maximum Input Power			12	dBm	6:1 VSWR, V <sub>CC</sub> = 3.3V, 25°C	
Maximum Input Power			5	dBm	10:1 VSWR, V <sub>CC</sub> = 3.3V, 25°C	
Bluetooth (Both 3.3V and 5.0V)					Temperature = -10°C to +70°C, V <sub>DD</sub> = 3.3V, 5.0V, C_BT = High, unless otherwise noted	
Input/Output Power	25	30		dBm		
Insertion Loss		0.7	0.9	dB		
BT Port Return Loss			-9.6	dB		
ANT Port Return Loss			-9.6	dB		
Isolation						
ANT-BT; Tx Mode		18		dB	PA_EN = High, C_BT = Low, C_RX = Low, LNA_EN = Low	
ANT-BT; Rx Gain Mode		25		dB	PA_EN = Low, C_BT = Low, C_RX = High, LNA_EN = High	
ANT-BT; Rx Bypass Mode		20		dB	PA_EN = Low, C_BT = Low, C_RX = High, LNA_EN = Low	
ANT-RX; Tx Mode		35		dB	PA_EN = High, C_BT = Low, C_RX = Low, LNA_EN = Low	
ANT-RX; BT Mode		25		dB	PA_EN = Low, C_BT = High, C_RX = Low, LNA_EN = Low	
ANT Port Return Loss			-9.6	dB		

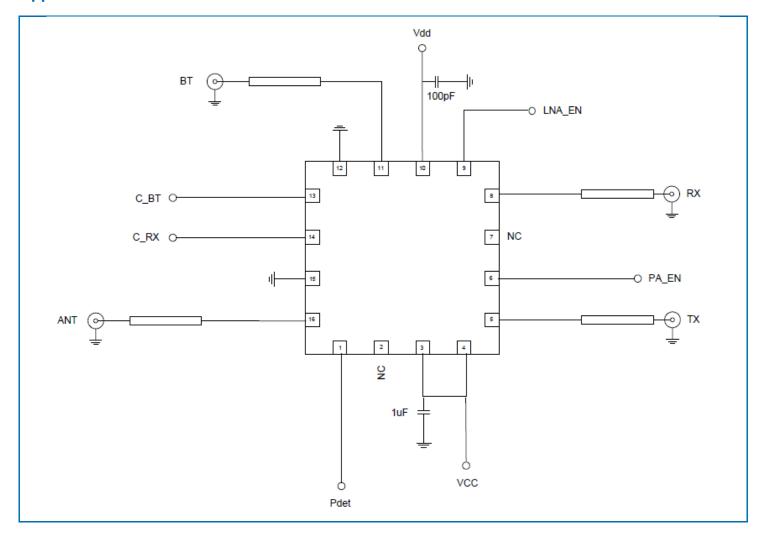


## **Switch Logic Control**

Operating Mode	PA_EN	LNA_EN	C_RX	C_BT
Standby	Low	Low	Low	Low
802.11b/g/n/ Tx	High	Low	Low	Low
802.11b/g/n/ Rx Gain	Low	High	High	Low
802.11b/g/n/ Rx Bypass	Low	Low	High	Low
BT Rx/ Tx	Low	Low	Low	High

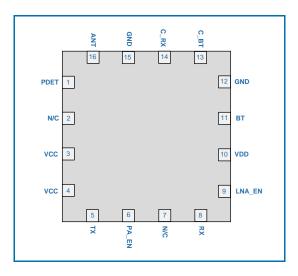
Note: High = 2.8V to VCC, Low = 0V to 0.2V

## **Applications Schematic**

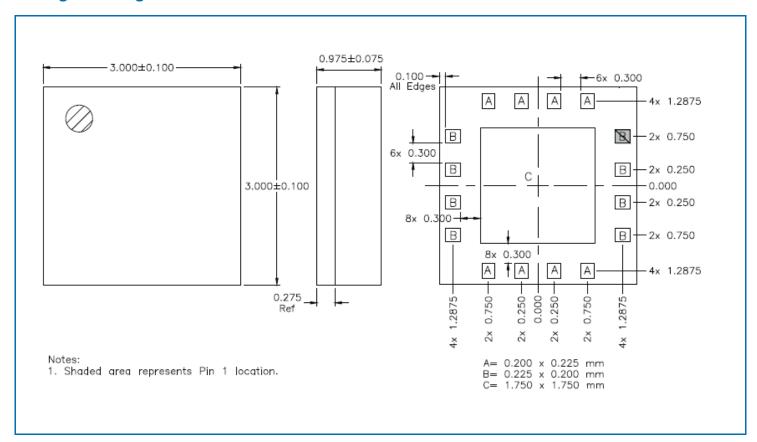




#### **Pin Out**

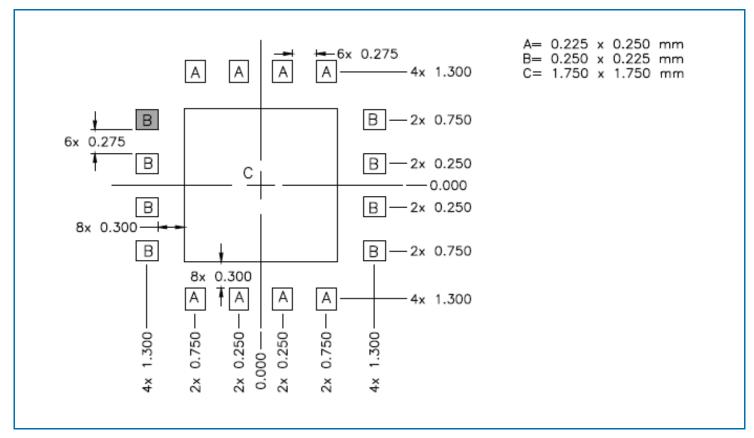


## **Package Drawing**





#### **PCB Pattern**



#### Note:

- 1. Shaded area represents Pin 1 location
- 2. Example of the number and size of vias can be found on the RFMD evaluation board layout.



## **Pin Names and Descriptions**

Pin	Name	Description
1	PDET	Power detector voltage for Tx section. PDET voltage varies with output power. May need external decoupling for noise decoupling.
2	NC	No Connect. This pin is not connected internally. It can be left floating or connected to ground.
3	VCC	Supply voltage for the PA. See applications schematic for biasing and bypassing components.
4	VCC	Supply voltage for the PA. See applications schematic for biasing and bypassing components.
5	TX	RF input port for the 802.11b/g/n PA. Input is matched to $50\Omega$ and DC block is provided internally.
6	PA_EN	Control voltage for the PA and Tx switch. See truth table for proper settings.
7	NC	No Connect. This pin is not connected internally. It can be left floating or connected to ground.
8	RX	RF output port for the 802.11b/g/n LNA. Input is matched to $50\Omega$ and DC block is provided internally.
9	LNA_EN	Control voltage for the LNA. When this pin is set to a LOW logic state, the bypass mode is enabled.
10	VDD	Supply voltage for the LNA. See applications schematic for biasing and bypassing components.
11	ВТ	RF Bidirectional port for Bluetooth <sup>®</sup> . Input is matched to $50\Omega$ and DC block is provided internally.
12	GND	Ground connection. This pin is not connected internally and can be left floating or connected to ground.
13	C_BT	Bluetooth® switch control pin. See Truth Table for proper level.
14	C_RX	Receive switch control pin. See Switch Truth Table for proper level.
15	GND	Ground connection. This pin is not connected internally and can be left floating or connected to ground.
16	ANT	RF bidirectional antenna port matched to $50\Omega$ and DC block is provided internally.
Pkg Base	GND	Ground connection. The backside of the package should be connected to the ground plane through a short path, i.e., PCB vias under the device are recommended.

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